

isc N-Channel MOSFET Transistor

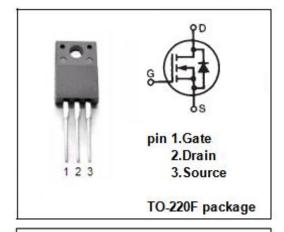
STF9NK90Z

FEATURES

- Drain Current : I_D= 8A@ T_C=25℃
- Drain Source Voltage
 - : V_{DSS}= 900V(Min)
- Static Drain-Source On-Resistance
- : $R_{DS(on)} = 1.3 \Omega (Max) @ V_{GS} = 10V$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

 motor drive, DC-DC converter, power switch and solenoid drive.



• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	900	V
V _{GSS}	Gate-Source Voltage	±30	V
I _D	Drain Current-Continuous;@Tc=25℃	8	А
I _{DM}	Drain Current-Single Pulsed	32	А
P _D	Total Dissipation	40	W
Tj	Operating Junction Temperature	-55~150	${\mathbb C}$
T _{stg}	Storage Temperature	-55~150	$^{\circ}$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	3.1	°C/W

F ○ ○ ○	ģ	- C - -S-	0		
L	H K	, R	;- L		
D		J	m]]	
	DIM	MIN			
	A	14.95	15.05	1	
	В	10.00	10.10	1	
	C	4.40	4.60	1	
	D	0.75	0.90	1	
	F	3.10	3.30	1	
	Н	3.70	3.90		
	J	0.50	0.70]	
	K	13.4	13.6 1.30		
	L	1.10	1.30		
	N	5.00	5.20		
	Q	2.70	2.90]	
	R	2.20	2.40		
	S	2.65	2.90		
	U	6.40	6.60		

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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 1mA	900	-	-	V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} ; I _D = 0.1mA	3	-	4.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D =3.6A	-	-	1.3	Ω
I _{GSS}	Gate-Source Leakage Current	V _{GS} =±20V;V _{DS} = 0V	-	-	±10	uA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 900V; V _{GS} = 0V	-	-	1	uA
V _{SD}	Diode forward voltage	I _{SD} = 8A, V _{GS} = 0 V	-	-	1.6	V

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